# FAIRCHILD

SEMICONDUCTOR®

# FJP5321

# **High Voltage and High Reliability**

- High speed Switching
- Wide Safe Operating Area



1.Base 2.Collector 3.Emitter

# NPN Triple Diffused Planar Silicon Transistor

Symbol	Parameter	Value	Units V	
V <sub>CBO</sub>	Collector-Base Voltage	800		
V <sub>CEO</sub>	Collector-Emitter Voltage	500	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7	V	
l <sub>C</sub>	Collector Current (DC)	5	А	
I <sub>CP</sub>	*Collector Current (Pulse)	10	А	
I <sub>B</sub>	Base Current (DC)	2	А	
I <sub>BP</sub>	*Base Current (Pulse)	4	А	
P <sub>C</sub>	Power Dissipation(T <sub>C</sub> =25°C)	100	W	
TJ	Junction Temperature	150	°C	
Т <sub>STG</sub>	Storage Temperature	- 55 ~ 150	٥°	

Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

<sup>I</sup> STG Storage Temperature \* Pulse Test: Pulse Width = 5ms, Duty Cycle≤10%

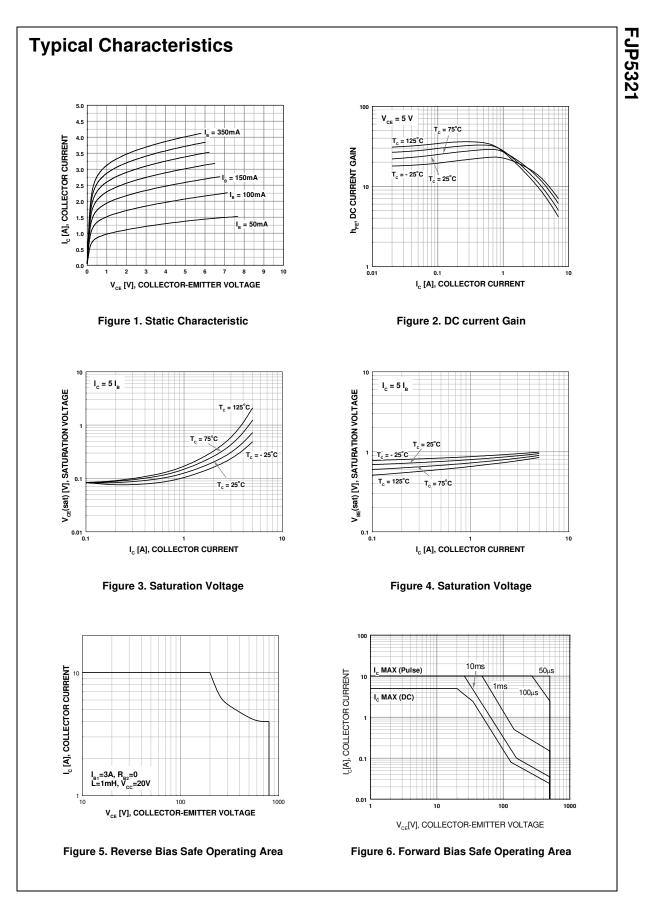
# Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	ymbol Parameter Test Condition		Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA, I <sub>E</sub> = 0	800	-	-	V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 5 {\rm mA}, \ I_{\rm B} = 0$	500	-	-	V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>C</sub> =1mA, I <sub>C</sub> = 0	7	-	-	V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 800V, I <sub>E</sub> = 0	-	-	100	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 7V, I_{C} = 0$	-	-	10	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 0.6A$	15	-	40	
h <sub>FE2</sub>		$V_{CE} = 5V, I_{C} = 3A$	8	-	-	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A, I <sub>B</sub> = 0.6A	-	-	1.0	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A, I <sub>B</sub> = 0.6A	-	-	1.5	V
f <sub>T</sub>	Current Gain bandwidth Product	$V_{CE}$ = 10V, $I_{C}$ = 0.6A	-	14	-	MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1MHz$	-	65	100	pF
C <sub>ib</sub>	Input Capacitance	$V_{EB} = 7V, I_{C} = 0, f = 1MHz$	-	1400	2000	pF
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = 125V, I <sub>C</sub> = 1A	-	-	0.5	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 0.2A$		-	6.5	μs
t <sub>F</sub>	Fall Time	R <sub>L</sub> = 125Ω	-	-	0.3	μs
t <sub>ON</sub>	Turn On Time	$V_{CC} = 250V, I_{C} = 4A$	-	-	0.5	μs
t <sub>STG</sub>	Storage Time	I <sub>B1</sub> = 0.8A, I <sub>B2</sub> = -1.6A	-	-	3.0	μs
t <sub>F</sub>	Fall Time	$R_{L} = 62.5\Omega$	-	-	0.3	μs

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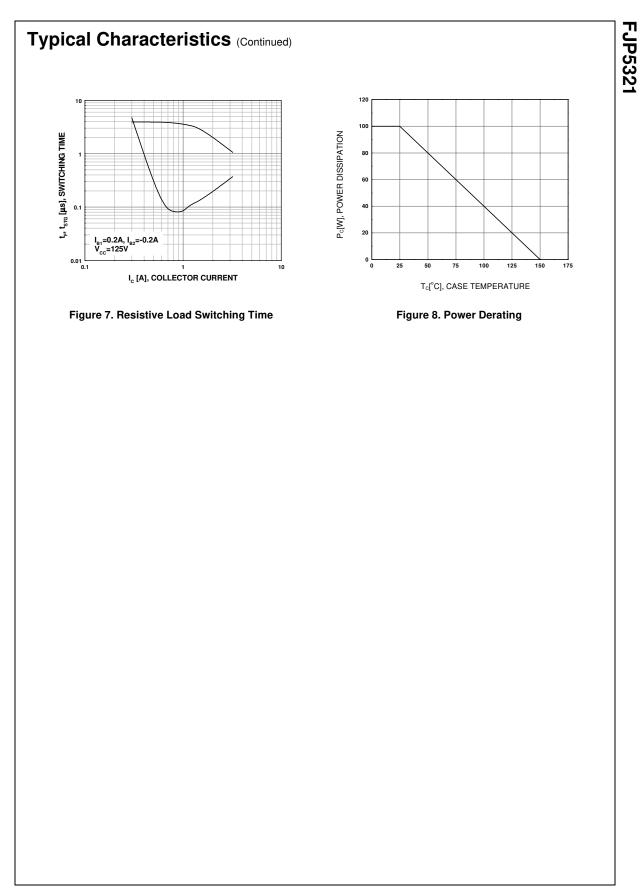
# FJP5321

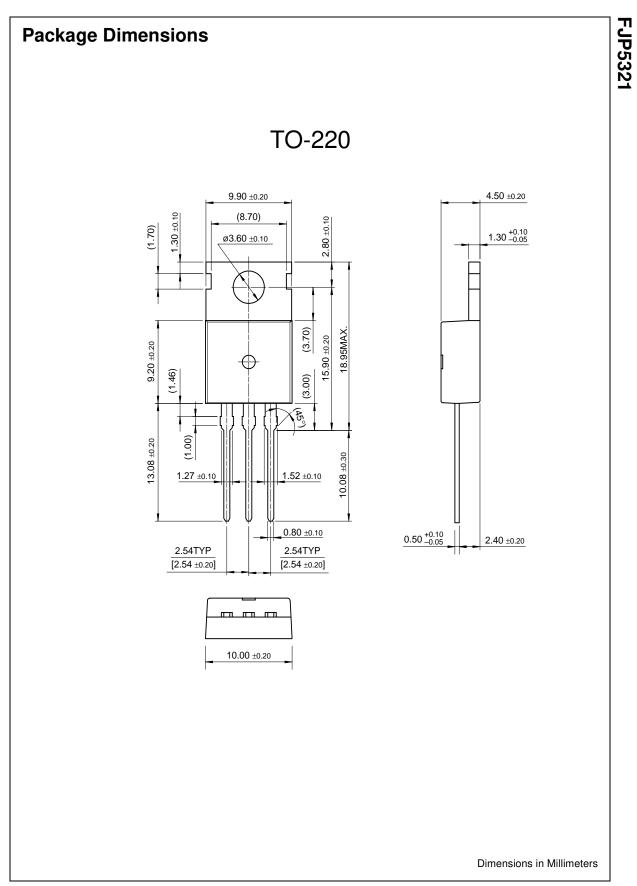
Symbol		Characteristics	Rating	Unit
l <sub>ejc</sub>	Thermal Resistance	Junction to Case	1.25	°C/W
еја Фја		Junction to Ambient	62.5	



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NPN Triple Diffused Planar Silicon Transistor



#### Features

- High speed Switching
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\* Fairchild 1,000 piece Budgetary Pricing

\*\* A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples

 ${m ar v}$  Indicates product with Pb-free second-level interconnect. For more information click here.

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